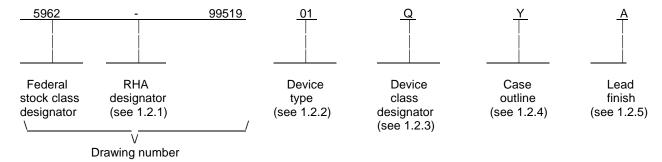
REV									F	REVISI	ONS										
REV	LTR					I	DESCR	RIPTIO	N					DA	TE (Y	R-MO-E	DA)		APPR	OVED	
REV	А	Corr	ected	typos	pos in table I and Figure 1 Terminal connections. ksr 01-08-27 Raymond Monnin							nin									
REV	В	Boile	erplate																		
SHEET	С	Upda	ated b	oilerpl	ate for	5 yea	ar revie	ew. Ih							11-1	1-02		С	harles	F. Sa	ffle
SHEET																					
REV																					
SHEET 15		С	С	С	С	С	С	С	С	С											
OF SHEETS SHEET 1 2 3 4 5 6 7 8 9 10 11 12 13 14 PMIC N/A PREPARED BY Kenneth Rice DLA LAND AND MARITIME COLUMBUS, OHIO 43218-3990 http://www.landandmaritime.dla.mil STANDARD MICROCIRCUIT DRAWING IS AVAILABLE FOR USE BY ALL DEPARTMENTS AND AGENCIES OF THE DEPARTMENTS AND AGENCIES OF THE DEPARTMENT OF DEFENSE MICROCIRCUIT, MEMORY, DIGITAL, CMOS, ELECTRICALLY ALTERABLE (IN-SYS REPROGRAMMABLE), 64 MACROCELL, PROGRAMMABLE LOGIC DEVICE, MONOLITHIC SILICON AMSC N/A REVISION LEVEL CHARD AND MARITIME COLUMBUS, OHIO 43218-3990 http://www.landandmaritime.dla.mil SYBIET CAGE CODE A 67268 5962-99519						19															
PMIC N/A PREPARED BY Kenneth Rice DLA LAND AND MARITIME COLUMBUS, OHIO 43218-3990 http://www.landandmaritime.dla.mil CHECKED BY Jeff Bowling APPROVED BY Raymond Monnin APPROVED BY Raymond Monnin MICROCIRCUIT, MEMORY, DIGITAL, CMOS, ELECTRICALLY ALTERABLE (IN-SYS REPROGRAMMABLE), 64 MACROCELL, PROGRAMMABLE), 64 MACROCELL, PROGRAMMABLE LOGIC DEVICE, MONOLITHIC SILICON AMSC N/A REVISION LEVEL C SIZE CAGE CODE A 67268 SHEET 1 OF 23	REV STATUS	3	<u>I</u>	1	REV	/		С	С	С	С	С	С	С	С	С	С	С	С	С	С
STANDARD MICROCIRCUIT DRAWING THIS DRAWING IS AVAILABLE FOR USE BY ALL DEPARTMENTS AND AGENCIES OF THE DEPARTMENT OF DEFENSE AMSC N/A Kenneth Rice CHECKED BY Jeff Bowling APPROVED BY Raymond Monnin APPROVED BY Raymond Monnin MICROCIRCUIT, MEMORY, DIGITAL, CMOS, ELECTRICALLY ALTERABLE (IN-SYS REPROGRAMMABLE), 64 MACROCELL, PROGRAMMABLE), 64 MACROCELL, PROGRAMMABLE LOGIC DEVICE, MONOLITHIC SILICON REVISION LEVEL C SIZE CAGE CODE A 67268 SHEET 1 OF 23	OF SHEETS				SHE	ET		1	2	3	4	5	6	7	8	9	10	11	12	13	14
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D000 F0DM 0000											SHE	ET		1	OF	23					

1. SCOPE

- 1.1 <u>Scope</u>. This drawing documents two product assurance class levels consisting of high reliability (device classes Q and M) and space application (device class V). A choice of case outlines and lead finishes are available and are reflected in the Part or Identifying Number (PIN). When available, a choice of Radiation Hardness Assurance (RHA) levels are reflected in the PIN.
 - 1.2 PIN. The PIN is as shown in the following example:



- 1.2.1 RHA designator. Device classes Q and V RHA marked devices meet the MIL-PRF-38535 specified RHA levels and are marked with the appropriate RHA designator. Device class M RHA marked devices meet the MIL-PRF-38535, appendix A specified RHA levels and are marked with the appropriate RHA designator. A dash (-) indicates a non-RHA device.
 - 1.2.2 <u>Device type(s)</u>. The device type(s) identify the circuit function as follows:

Device type	Generic number	Circuit function	Toggle Speed (MHz)
01	CY37064	64 Macrocell CPLD	125
02	CY37064	64 Macrocell CPLD	154

1.2.3 <u>Device class designator</u>. The device class designator is a single letter identifying the product assurance level as follows:

<u>Device class</u> <u>Device requirements documentation</u>

Vendor self-certification to the requirements for MIL-STD-883 compliant, non-JAN class level B microcircuits in accordance with MIL-PRF-38535,

appendix A

Q or V Certification and qualification to MIL-PRF-38535

1.2.4 Case outline(s). The case outline(s) are as designated in MIL-STD-1835 and as follows:

Outline letter	Descriptive designator	<u>Terminals</u>	Package style
Υ	GQCC1-J44	44	J-leaded chip carrier

1.2.5 <u>Lead finish</u>. The lead finish is as specified in MIL-PRF-38535 for device classes Q and V or MIL-PRF-38535, appendix A for device class M.

STANDARD MICROCIRCUIT DRAWING	SIZE A		5962-99519
DLA LAND AND MARITIME COLUMBUS, OHIO 43218-3990		REVISION LEVEL C	SHEET 2

M

1.3 Absolute maximum ratings. 1/

1.4 Recommended operating conditions. 4/

2. APPLICABLE DOCUMENTS

2.1 <u>Government specification, standards, and handbooks</u>. The following specification, standards, and handbooks form a part of this drawing to the extent specified herein. Unless otherwise specified, the issues of these documents are those cited in the solicitation or contract.

DEPARTMENT OF DEFENSE SPECIFICATION

MIL-PRF-38535 - Integrated Circuits, Manufacturing, General Specification for.

DEPARTMENT OF DEFENSE STANDARDS

MIL-STD-883 - Test Method Standard Microcircuits.

MIL-STD-1835 - Interface Standard For Microcircuit Case Outlines.

DEPARTMENT OF DEFENSE HANDBOOKS

MIL-HDBK-103 - List of Standard Microcircuit Drawings (SMD's).

MIL-HDBK-780 - Standard Microcircuit Drawings.

(Copies of these documents are available online at https://assist.daps.dla.mil/quicksearch/ or from the Standardization Document Order Desk, 700 Robbins Avenue, Building 4D, Philadelphia, PA 19111-5094.)

 $\underline{2}$ / Must withstand the added P_D due to short circuit test (e.g., I_{OS}).

^{4/} All voltage values in this drawing are with respect to V_{SS}.

STANDARD MICROCIRCUIT DRAWING	SIZE A		5962-99519
DLA LAND AND MARITIME COLUMBUS, OHIO 43218-3990		REVISION LEVEL C	SHEET 3

^{1/} Stresses above the absolute maximum rating may cause permanent damage to the device. Extended operation at the maximum levels may degrade performance and affect reliability.

Maximum junction temperature shall not be exceeded except for allowable short duration burn-in screening conditions in accordance with method 5004 of MIL-STD-883.

2.2 <u>Non-Government publications</u>. The following document(s) form a part of this document to the extent specified herein. Unless otherwise specified, the issues of the documents are the issues of the documents cited in the solicitation.

AMERICAN SOCIETY FOR TESTING AND MATERIALS (ASTM)

ASTM Standard F1192 - Standard Guide for the Measurement of Single Event Phenomena (SEP) Induced by Heavy Ion Irradiation of Semiconductor Devices.

(Applications for copies of ASTM publications should be addressed to: ASTM International, PO Box C700, 100 Barr Harbor Drive, West Conshohocken, PA 19428-2959; http://www.astm.org.)

JEDEC INTERNATIONAL (JEDEC)

JEDEC Standard No. 78 - IC Latch-Up Test.

(Copies of this document are available online at www.jedec.org/ or from JEDEC – Solid State Technology Association, 3103 North 10th Street, Suite 240-S, Arlington, VA 22201).

(Non-Government standards and other publications are normally available from the organizations that prepare or distribute the documents. These documents also may be available in or through libraries or other informational services.)

2.3 <u>Order of precedence</u>. In the event of a conflict between the text of this drawing and the references cited herein, the text of this drawing takes precedence. Nothing in this document, however, supersedes applicable laws and regulations unless a specific exemption has been obtained.

3. REQUIREMENTS

- 3.1 <u>Item requirements</u>. The individual item requirements for device classes Q and V shall be in accordance with MIL-PRF-38535 and as specified herein or as modified in the device manufacturer's Quality Management (QM) plan. The modification in the QM plan shall not affect the form, fit, or function as described herein. The individual item requirements for device class M shall be in accordance with MIL-PRF-38535, appendix A for non-JAN class level B devices and as specified herein.
- 3.2 <u>Design, construction, and physical dimensions</u>. The design, construction, and physical dimensions shall be as specified in MIL-PRF-38535 and herein for device classes Q and V or MIL-PRF-38535, appendix A and herein for device class M.
 - 3.2.1 Case outline(s). The case outline(s) shall be in accordance with 1.2.4 herein.
 - 3.2.2 <u>Terminal connections</u>. The terminal connections shall be as specified on figure 1.
- 3.3 <u>Electrical performance characteristics and postirradiation parameter limits</u>. Unless otherwise specified herein, the electrical performance characteristics and postirradiation parameter limits are as specified in table I and shall apply over the full case operating temperature range.
- 3.4 <u>Electrical test requirements</u>. The electrical test requirements shall be the subgroups specified in table IIA. The electrical tests for each subgroup are defined in table I.
- 3.5 <u>Marking</u>. The part shall be marked with the PIN listed in 1.2 herein. In addition, the manufacturer's PIN may also be marked. For packages where marking of the entire SMD PIN number is not feasible due to space limitations, the manufacturer has the option of not marking the "5962-" on the device. For RHA product using this option, the RHA designator shall still be marked. Marking for device classes Q and V shall be in accordance with MIL-PRF-38535. Marking for device class M shall be in accordance with MIL-PRF-38535, appendix A.
- 3.5.1 <u>Certification/compliance mark</u>. The certification mark for device classes Q and V shall be a "QML" or "Q" as required in MIL-PRF-38535. The compliance mark for device class M shall be a "C" as required in MIL-PRF-38535, appendix A.
- 3.6 <u>Certificate of compliance</u>. For device classes Q and V, a certificate of compliance shall be required from a QML-38535 listed manufacturer in order to supply to the requirements of this drawing (see 6.6.1 herein). For device class M, a certificate of compliance shall be required from a manufacturer in order to be listed as an approved source of supply in MIL-HDBK-103 (see 6.6.2 herein). The certificate of compliance submitted to DLA Land and Maritime -VA prior to listing as an approved source of supply for this drawing shall affirm that the manufacturer's product meets, for device classes Q and V, the requirements of MIL-PRF-38535 and herein or for device class M, the requirements of MIL-PRF-38535, appendix A and herein.

STANDARD MICROCIRCUIT DRAWING	SIZE A		5962-99519
DLA LAND AND MARITIME COLUMBUS, OHIO 43218-3990		REVISION LEVEL C	SHEET 4

- 3.7 <u>Certificate of conformance</u>. A certificate of conformance as required for device classes Q and V in MIL-PRF-38535 or for device class M in MIL-PRF-38535, appendix A shall be provided with each lot of microcircuits delivered to this drawing.
- 3.8 <u>Notification of change for device class M.</u> For device class M, notification to DLA Land and Maritime-VA of change of product (see 6.2 herein) involving devices acquired to this drawing is required for any change that affects this drawing.
- 3.9 <u>Verification and review for device class M.</u> For device class M, DLA Land and Maritime, DLA Land and Maritime's agent, and the acquiring activity retain the option to review the manufacturer's facility and applicable required documentation. Offshore documentation shall be made available onshore at the option of the reviewer.
- 3.10 <u>Microcircuit group assignment for device class M.</u> Device class M devices covered by this drawing shall be in microcircuit group number 42 (see MIL-PRF-38535, appendix A).
- 3.11 <u>Processing CPLDs</u>. All testing requirements and quality assurance provisions herein shall be satisfied by the manufacturer prior to delivery.
- 3.11.1 <u>Erasure of CPLDs</u>. When specified, devices shall be erased in accordance with the procedures and characteristics specified in 4.6 herein.
- 3.11.2 <u>Programmability of CPLDs</u>. When specified, devices shall be programmed to the specified pattern using the procedures and characteristics specified in 4.7 herein.
- 3.11.3 <u>Verification of erasure or programmed CPLDs</u>. When specified, devices shall be verified as either programmed (see 4.7 herein) to the specified pattern or erased (see 4.6 herein). As a minimum, verification shall consist of performing a functional test (subgroup 7) to verify that all bits are in the proper state. Any bit that does not verify to be in the proper state shall constitute a device failure, and shall be removed from the lot.
- 3.12 <u>Endurance</u>. A reprogrammability test shall be completed as part of the vendor's reliability monitor. This reprogrammability test shall be done only for initial characterization and after any design or process changes which may affect the reprogrammability of the device. The methods and procedures may be vendor specific, but shall be under document control and shall be made available upon request.
- 3.13 <u>Data Retention</u>. A data retention stress test shall be completed as part of the vendor's reliability monitors. This test shall be done for initial characterization and after any design or process changes which may affect data retention. The methods and procedures may be vendor specific, but shall guarantee the number of years listed in section 1.3 herein over the full military temperature range. The vendor's procedure shall be kept under document control and shall be made available upon request of the acquiring or preparing activity, along with the test data.

STANDARD MICROCIRCUIT DRAWING	SIZE A		5962-99519
DLA LAND AND MARITIME COLUMBUS, OHIO 43218-3990		REVISION LEVEL C	SHEET 5

TABLE I. <u>Electrical performance characteristics</u>.

Test	Symbol	Conditions	Group A	Device	Li	mits	Unit
		$4.5 \text{ V} \leq \text{V}_{\text{CC}} \leq 5.5 \text{ V}$ $-55^{\circ}\text{C} \leq \text{T}_{\text{C}} \leq +125^{\circ}\text{C}$ unless otherwise specified	Subgroups	type	Min	Max	
High Level output voltage	V _{OH}	$V_{CC} = 4.5 \text{ V}, V_{IL} = 0.8 \text{V}$ $I_{OH} = -2.0 \text{ mA}, V_{IH} = 2.0 \text{ V}$ 1/	1, 2, 3	All	2.4		V
High Level output voltage with Output	V _{OHZ}	$V_{CC} = 5.5 \text{ V}, V_{IL} = 0.8 \text{V}$ $I_{OH} = 0 \mu\text{A}, V_{IH} = 2.0 \text{ V}$ $\underline{3}/$				4.5	V
Disabled <u>2</u> /		$V_{CC} = 5.5 \text{ V}, V_{IL} = 0.8 \text{V}$ $I_{OH} = -150 \mu\text{A}, V_{IH} = 2.0 \text{ V}$ 3/				3.6	V
Low level output voltage	V _{OL}	$V_{CC} = 4.5 \text{ V}, I_{OL} = 12.0 \text{ mA}$ $V_{IL} = 0.8 \text{ V}, V_{IH} = 2.0 \text{ V}$ 1/				0.5	V
High level input voltage <u>4</u> /	V _{IH}				2	V _{CC} + 0.5 V	V
Low level input voltage 4/	V _{IL}				-0.5	0.8	V
Input load current	I _{IX}	$V_{IN} = 0 \text{ V or } V_{CC}$, with Busshold off			-10	+10	μА
Output leakage current	l _{OZ}	V_{CC} = 5.5 V, V_{O} = GND or V_{CC} , Output disabled, Busshold off			-50	+50	μА
Output short circuit current 2/5/	I _{os}	$V_{CC} = 5.5 \text{ V}, V_{OUT} = 0.5 \text{ V}$			-30	-160	mA
Power supply current <u>6</u> /	I _{CC}	$V_{CC} = 5.5 \text{ V}, I_{OUT} = 0 \text{ mA}, \ V_{IN} = 0 \text{ V} \text{ and } 5.5 \text{ V} \ f = 1.0 \text{ MHz}$				100	mA
Input bus hold low sustained current <u>2</u> /	I _{BHL}	$V_{CC} = 4.5 \text{ V}, V_{IL} = 0.8 \text{ V}$			+75		μΑ
Input bus hold high sustained current <u>2</u> /	Івнн	$V_{CC} = 4.5 \text{ V}, V_{IH} = 2.0 \text{ V}$			-75		μΑ
Input bus hold low sustained overdrive current <u>2</u> /	I _{BHLO}	V _{CC} = 5.5 V				+500	μА
Input bus hold high sustained overdrive current <u>2</u> /	І _{внно}	V _{CC} = 5.5 V				-500	μА

See footnotes at end of table.

STANDARD MICROCIRCUIT DRAWING	SIZE A		5962-99519
DLA LAND AND MARITIME COLUMBUS, OHIO 43218-3990		REVISION LEVEL C	SHEET 6

TABLE I. <u>Electrical performance characteristics</u> - Continued.

Test	Symbol	Conditions	Group A	Device	Liı	mits	Unit
		$4.5 \text{ V} \leq \text{V}_{\text{CC}} \leq 5.5 \text{ V}$ $-55^{\circ}\text{C} \leq \text{T}_{\text{C}} \leq +125^{\circ}\text{C}$ unless otherwise specified	Subgroups	type	Min	Max	
Input capacitance 2/	C _{IN}	See 4.4.1e, VIN = 5.0 V, f = 1 MHz, TA = 25°C	4	All		12	pF
Output capacitance 2/	Соит	See 4.4.1e, VIN = 5.0 V, f = 1 MHz, TA = 25°C	4	All		12	pF
Dual functional pin capacitance <u>2</u> /	C _{DP}	See 4.4.1e, VIN = 5.0 V, f = 1 MHz, TA = 25°C	4	All		16	pF
Functional test		See 4.4.1c	7,8A,8B	All			
Input to combinatorial	t _{PD}	See figures 2 and 3	9, 10, 11	01		10	ns
output <u>7</u> / <u>8</u> / <u>9</u> / <u>10</u> /		(circuit A)		02		7.5	
Input to output through	t _{PDL}	See figures 2 and 3		01		16.5	
transparent input or output latch 2/ 7/ 8/ 9/10/		(circuit A)	9, 10, 11	02		14.5	
Input to output through	t _{PDLL}			01		17.5	
transparent input and output latch 2/ 7/ 8/ 9/ 10/				02		15.5	
Input to output enable	t _{EA}	See figures 2 and 3		01		14	
see figure 2 test waveforms <u>2</u> / <u>7</u> / <u>8</u> / <u>9</u> / <u>10</u> /		(circuit B)		02		11	
Input to output disable	t _{ER}			01		14	
see figure 2 test waveforms 2/ 7/ 8/				02		11	
Clock or Latch enable	t _{WH}	See figures 2 and 3		01	3		
input High time 2/ 7/		(circuit A)		02	2.5		
Clock or latch enable	t _W ∟			01	3		
input low time 2/ 7/				02	2.5		
Input register or latch set-up time 2/ 7/	tıs			All	2		
Input register or latch hold time 2/ 7/	t _{IH}			All	2		
Input register clock or latch enable to	t _{ICO}			01		12.5	
combinatorial output <u>2</u> / <u>7</u> / <u>8</u> / <u>9</u> / <u>10</u> /				02		11	

See footnotes at end of table.

STANDARD MICROCIRCUIT DRAWING	SIZE A		5962-99519
DLA LAND AND MARITIME COLUMBUS, OHIO 43218-3990		REVISION LEVEL C	SHEET 7

TABLE I. <u>Electrical performance characteristics</u> - Continued.

Test	Symbol	Conditions	Group A	Device	Lir	mits	Unit
		$4.5 \text{ V} \leq \text{V}_{\text{CC}} \leq 5.5 \text{ V}$ $-55^{\circ}\text{C} \leq \text{T}_{\text{C}} \leq +125^{\circ}\text{C}$ unless otherwise specified	Subgroups	type	Min	Max	
Input register clock or	t _{ICOL}	See figures 2 and 3	9, 10, 11	01		16	ns
latch enable to output through transparent output latch 2/7/8/9/10/		(circuit A)		02		12	
Synchronous clock or latch enable to output 7/ 9/10/	tco			01 02		6.5 4.5	ns
Register or latch data hold time 7/	t _H			All	0		ns
Set-up time from input to	ts			01	5.5		ns
synchronous clock or latch enable 7/8/				02	5.0		
Set-up time from input	t _{SL}			01	10		ns
through transparent latch to output register Synchronous clock or latch enable 2/7/8/				02	8.5		
Output Synchronous	t _{CO2}			01		14	ns
clock or latch enable to combinatorial output delay (through memory array) 2/ 7/ 8/ 9/ 10/				02		11	
Output Synchronous	t _{SCS}			01	8		ns
clock or latch enable to output synchronous clock or latch enable (through logic array) 7/ 8/				02	6.5		
Hold time for input through transparent latch from output register Synchronous clock or latch enable 2/7/	t _{HL}			All	0		ns
Maximum frequency with internal feedback (lesser	f _{MAX1}			01	125		MHz
of 1/t _{SCS} , 1/(t _S + t _H), or 1/t _{CO}) <u>2</u> / <u>7</u> /				02	154		

See footnotes at end of table.

STANDARD MICROCIRCUIT DRAWING	SIZE A		5962-99519
DLA LAND AND MARITIME COLUMBUS, OHIO 43218-3990		REVISION LEVEL C	SHEET 8

TABLE I. <u>Electrical performance characteristics</u> - Continued.

Test	Symbol	Conditions	Group A	Device	Lin	nits	Unit
		$4.5 \text{ V} \leq \text{V}_{\text{CC}} \leq 5.5 \text{ V}$ $-55^{\circ}\text{C} \leq \text{T}_{\text{C}} \leq +125^{\circ}\text{C}$ unless otherwise specified	Subgroups	type	Min	Max	
Maximum frequency	f _{MAX2}	See figures 2 and 3	9, 10, 11	01	154		MHz
data path in output register/latched mode (lesser of 1/(t _{WL+} t _{WH}), 1/(t _{s+tH}), or 1/t _{CO}) <u>2</u> / <u>7</u> /		(circuit A)		02	200		
Maximum frequency with	f _{MAX3}			01	83		
external feedback (lesser of $1/(t_{CO} + t_S)$,or $1/(t_{WL} + t_{WH})$ $2/7/$				02	105		
Maximum frequency in	f _{MAX4}			01	118		
pipelined mode (lesser of $1/(t_{CO} + t_{IS})$, $1/t_{ICS}$, $1/(t_{WL} + t_{WH})$, $1/(t_{IS} + t_{IH})$, or $1/t_{SCS}$ $2/T/$				02	154		
Input register	t _{ICS}			01	8		ns
Synchronous clock to output register clock 2/ 7/8/				02	6		
Asynchronous preset width 2/7/	t_{PW}			01	10		
widii <u>zi ii</u>				02	8		
Asynchronous preset recovery time 2/7/8/	t _{PR}			01 02	12 10		
Asynchronous preset to	t _{PO}			01	10	15	
output <u>2</u> / <u>7</u> / <u>8</u> / <u>9</u> / <u>10</u> /	•••0			02		13	
Asynchronous reset	t _{RW}			01	10		
width <u>2</u> / <u>7</u> /				02	8		
Asynchronous reset	t _{RR}			01	12		
recovery time <u>2/ 7/ 8/</u>				02	10		
Asynchronous reset to	t _{RO}			01		15	
output <u>2</u> / <u>7</u> / <u>8</u> / <u>9</u> / <u>10</u> /				02		13	
Product term clock or	t _{COPT}			01		13	
latch enable (PTCLK) to output 2/ 7/ 8/ 9/ 10/				02		10	
Register or latch data hold time <u>2</u> / <u>7</u> /	t _{HPT}			01	5.0		
HOIG GITTE				02	2.5		
Set-up time from input to	t _{SPT}			01	5.0		
product term clock or latch enable (PTCLK) 2/ 7/				02	2.5		

See footnotes at the end of table.

STANDARD MICROCIRCUIT DRAWING	SIZE A		5962-99519
DLA LAND AND MARITIME COLUMBUS, OHIO 43218-3990		REVISION LEVEL C	SHEET 9

TABLE I. <u>Electrical performance characteristics</u> - Continued.

Test	Symbol	Conditions	Group A	Device	Lin	nits	Unit
		$4.5 \text{ V} \leq \text{V}_{\text{CC}} \leq 5.5 \text{ V}$ $-55^{\circ}\text{C} \leq \text{T}_{\text{C}} \leq +125^{\circ}\text{C}$ unless otherwise specified	Subgroups	type	Min	Max	
Set-up time for buried register used as an input register from input to product term clock or latch enable (PTCLK) 2/7/8/	t _{ISPT}	See figures 2 and 3 (circuit A)	9, 10, 11	All	0		ns
Buried register used as	t _{IHPT}			01	9		
an input register or latch data hold time 2/7/				02	6.5		
Product term clock or	t _{CO2PT}			01		19	
latch enable (PTCLK) to output delay (through logic array) 2/ 7/ 8/ 9/10/				02		15	
Low power adder 2/7/	t_{LP}			All		2.5	
Slow output slew rate adder 2/7/	t _{SLEW}			All		3.0	
3.3 V I/O mode timing adder <u>2</u> / <u>7</u> /	t _{3.31O}			All		0.3	
Set-up time from TDI and TMS to TCK 2/7/	t _{S JTAG}			All	0		
Hold time on TDI and TMS <u>2</u> / <u>7</u> /	t _{H JTAG}			All	20		
Falling edge of TCK to TDO 2/7/	t _{CO JTAG}			All		20	
Maximum JTAG tap controller frequency 2/7/	f_{JTAG}			All		20	MHz

- $\underline{1}$ / $I_{OH} = -2$ mA, $I_{OL} = +2$ mA for TDO.
- 2/ Tested initially and after any design or process changes that affect this parameter.
- 3/ When the I/O is output disabled, the bus-hold circuit can weakly pull the I/O to a maximum of 3.6 V if no leakage current is allowed. This voltage is lowered significantly by a small leakage current. Note that all I/Os are output disabled during ISR programming. Contact manufacturer for additional information.
- 4/ These are absolute values with respect to device ground, and all overshoots due to system or tester noise are included.
- 5/ Not more than one output should be tested at a time. Duration of the short circuit should not exceed 1 second. $V_{OUT} = 0.5 \text{ V}$ has been chosen to avoid test problems caused by tester ground degradation.
- 6/ Measured under AC conditions. Program pattern using 16-bit counter per logic block or equivalent.
- 7/ All AC parameters are measured with 2 outputs switching, and 35 pF AC test load.
- 8/ Logic blocks operating in low power mode, add t_{LP} to this spec.
- 9/ Outputs using slow output slew rate, add t_{SLEW} to this spec.
- $\underline{10}$ / When V_{CCO} = 3.3 V add t_{3.3IO} to this spec.

STANDARD MICROCIRCUIT DRAWING	SIZE A		5962-99519
DLA LAND AND MARITIME COLUMBUS, OHIO 43218-3990		REVISION LEVEL C	SHEET 10

4. VERIFICATION

- 4.1 <u>Sampling and inspection</u>. For device classes Q and V, sampling and inspection procedures shall be in accordance with MIL-PRF-38535 or as modified in the device manufacturer's Quality Management (QM) plan. The modification in the QM plan shall not affect the form, fit, or function as described herein. For device class M, sampling and inspection procedures shall be in accordance with MIL-PRF-38535, appendix A.
- 4.2 <u>Screening</u>. For device classes Q and V, screening shall be in accordance with MIL-PRF-38535, and shall be conducted on all devices prior to qualification and technology conformance inspection. For device class M, screening shall be in accordance with method 5004 of MIL-STD-883, and shall be conducted on all devices prior to quality conformance inspection.

4.2.1 Additional criteria for device class M.

- a. Delete the sequence specified as initial (preburn-in) electrical parameters through interim (postburn-in) electrical parameters of method 5004 and substitute lines 1 through 6 of table IIA herein.
- b. The test circuit shall be maintained by the manufacturer under document revision level control and shall be made available to the preparing or acquiring activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in method 1015.
 - (1) Dynamic burn-in (method 1015 of MIL-STD-883, test condition D; for circuit, see 4.2.1b herein).
- c. Interim and final electrical parameters shall be as specified in table IIA herein.

4.2.2 Additional criteria for device classes Q and V.

- a. The burn-in test duration, test condition and test temperature, or approved alternatives shall be as specified in the device manufacturer's QM plan in accordance with MIL-PRF-38535. The burn-in test circuit shall be maintained under document revision level control of the device manufacturer's Technology Review Board (TRB) in accordance with MIL-PRF-38535 and shall be made available to the acquiring or preparing activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in method 1015 of MIL-STD-883.
- b. Interim and final electrical test parameters shall be as specified in table IIA herein.
- c. Additional screening for device class V beyond the requirements of device class Q shall be as specified in MIL-PRF-38535, appendix B.
- 4.3 <u>Qualification inspection for device classes Q and V</u>. Qualification inspection for device classes Q and V shall be in accordance with MIL-PRF-38535. Inspections to be performed shall be those specified in MIL-PRF-38535 and herein for groups A, B, C, D, and E inspections (see 4.4.1 through 4.4.4).
- 4.4 <u>Conformance inspection</u>. Technology conformance inspection for classes Q and V shall be in accordance with MIL-PRF-38535 including groups A, B, C, D, and E inspections and as specified herein except where option 2 of MIL-PRF-38535 permits alternate in-line control testing. Quality conformance inspection for device class M shall be in accordance with MIL-PRF-38535, appendix A and as specified herein. Inspections to be performed for device class M shall be those specified in method 5005 of MIL-STD-883 and herein for groups A, B, C, D, and E inspections (see 4.4.1 through 4.4.4).

4.4.1 Group A inspection.

- a. Tests shall be as specified in table II herein.
- b. Subgroups 5 and 6 of table I of method 5005 of MIL-STD-883 shall be omitted.
- c. For device class M, subgroups 7 and 8 tests shall be sufficient to verify the truth table. For device classes Q and V, subgroups 7 and 8 shall include verifying the functionality of the device.

STANDARD MICROCIRCUIT DRAWING	SIZE A		5962-99519
DLA LAND AND MARITIME		REVISION LEVEL	SHEET
COLUMBUS, OHIO 43218-3990		C	11

- d. O/V (latch-up) tests shall be measured only for initial qualification and after any design or process changes which may affect the performance of the device. For device class M, procedures and circuits shall be maintained under document revision level control by the manufacturer and shall be made available to the preparing activity or acquiring activity upon request. For device classes Q and V, the procedures and circuits shall be under the control of the device manufacturer's TRB in accordance with MIL-PRF-38535 and shall be made available to the preparing activity or acquiring activity upon request. Testing shall be on all pins, on five devices with zero failures. Latch-up test shall be considered destructive. Information contained in JEDEC Standard EIA/JESD78 may be used for reference.
- e. Subgroup 4 (C_{IN} and C_{OUT} measurements) shall be measured only for initial qualification and after any process or design changes which may affect input or output capacitance. Capacitance shall be measured between the designated terminal and GND at a frequency of 1 MHz. Sample size is 15 devices with no failures, and all input and output terminals tested.
- 4.4.2 <u>Group C inspection</u>. The group C inspection end-point electrical parameters shall be as specified in table IIA herein.
 - 4.4.2.1 Additional criteria for device class M . Steady-state life test conditions, method 1005 of MIL-STD-883:
 - a. Test condition D. The test circuit shall be maintained by the manufacturer under document revision level control and shall be made available to the preparing or acquiring activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in method 1005
 - b. $T_A = +125$ °C, minimum.
 - c. Test duration: 1,000 hours, except as permitted by method 1005 of MIL-STD-883.
- 4.4.2.2 <u>Additional criteria for device classes Q and V.</u> The steady-state life test duration, test condition and test temperature, or approved alternatives shall be as specified in the device manufacturer's QM plan in accordance with MIL-PRF-38535. The test circuit shall be maintained under document revision level control by the device manufacturer's TRB in accordance with MIL-PRF-38535 and shall be made available to the acquiring or preparing activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in method 1005 of MIL-STD-883.
- 4.4.3 <u>Group D inspection</u>. The group D inspection end-point electrical parameters shall be as specified in table IIA herein.
- 4.4.4 <u>Group E inspection</u>. Group E inspection is required only for parts intended to be marked as radiation hardness assured (see 3.5 herein).
 - a. End-point electrical parameters shall be as specified in table IIA herein.
 - b. For device classes Q and V, the devices or test vehicle shall be subjected to radiation hardness assured tests as specified in MIL-PRF-38535 for the RHA level being tested. For device class M, the devices shall be subjected to radiation hardness assured tests as specified in MIL-PRF-38535, appendix A for the RHA level being tested. All device classes must meet the postirradiation end-point electrical parameter limits as defined in table I at T_A = +25°C ±5°C, after exposure, to the subgroups specified in table IIA herein.

STANDARD MICROCIRCUIT DRAWING	SIZE A		5962-99519
DLA LAND AND MARITIME COLUMBUS, OHIO 43218-3990		REVISION LEVEL C	SHEET 12

TABLE IIA. Electrical test requirements. 1/2/3/4/5/6/7/

Line	Test	Subgroups (in accordance with MIL-STD-883, method 5005, table I)	(in accor	groups dance with 3535, table III
no.	requirements	Device Class M	Device Class Q	Device Class V
1	Interim electrical parameters (see 4.2)			1, 7, 9 or 2, 8A, 10
2	Static burn-in (Method 1015)	Not Required	Not Required	Required
3	Same as line 1			1*, 7* Δ
4	Dynamic burn-in (Method 1015)	Required	Required	Required
5	Final electrical parameters	1*,2,3,7*, 8A,8B,9,10, 11	1*,2,3,7*, 8A,8B,9,10, 11	1*,2,3,7*, 8A,8B,9,10, 11
6	Group A test requirements	1*,2,3,4**,7, 8A,8B,9,10, 11	1*,2,3,4**,7, 8A,8B,9,10, 11	1*,2,3,4**,7, 8A,8B,9,10, 11
7	Group C end-point electrical parameters	2,3,7, 8A,8B	2,3,7, 8A,8B	1,2,3,7, 8A,8B,9, 10,11 Δ
8	Group D end-point Electrical Parameters	2,3, 8A,8B	2,3, 8A,8B	2,3, 8A,8B
9	Group E end-point electrical parameters	1,7,9	1,7,9	1,7,9

- 1/ Blank spaces indicate tests are not applicable.
 2/ Any or all subgroups may be combined when using high-speed testers.
 3/ Subgroups 7 and 8 functional tests shall verify the truth table.
- 4/ * indicates PDA applies to subgroup 1 and 7.
- 5/ ** see 4.4.1e.
- 6/ \(\Delta \) indicates delta limit (see table IIB) shall be required where specified, and the delta values shall be computed with reference to the previous interim electrical parameters (see line 1).
- <u>7</u>/ See 4.4.1d.

TABLE IIB. Delta limits at +25°C.

Parameter <u>1</u> /	Device types
	All
l _{oz}	± 10% of the specified value in table I
I _{IX}	± 10% of the specified value in table I

1/ The above parameter shall be recorded before and after the required burn-in and life tests to determine the delta Δ .

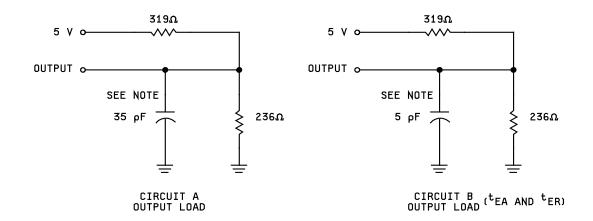
STANDARD MICROCIRCUIT DRAWING	SIZE A		5962-99519
DLA LAND AND MARITIME COLUMBUS, OHIO 43218-3990		REVISION LEVEL C	SHEET 13

Case outline Y

Device type	All	Device type	All
Terminal number	Terminal symbol	Terminal number	Terminal symbol
1 2 3 4 5 6 7 8 9 10 11 12 13 14 15 16 17 18 19 20 21 22	GND I/O I/O I/O I/O I/O I/O/TCK I/O CLK/I JTAGEN GND CLK/I I/O I/O I/O I/O I/O I/O I/O I/O I/O I	23 24 25 26 27 28 29 30 31 32 33 34 35 36 37 38 39 40 41 42 43 44	GND I/O

FIGURE 1. Terminal connections.

STANDARD MICROCIRCUIT DRAWING	SIZE A		5962-99519
DLA LAND AND MARITIME COLUMBUS, OHIO 43218-3990		REVISION LEVEL C	SHEET 14



NOTE: INCLUDING SCOPE AND JIG (MINIMUM VALUES).

FIGURE 2. Output load circuits and test conditions.

STANDARD MICROCIRCUIT DRAWING	SIZE A		5962-99519
DLA LAND AND MARITIME		REVISION LEVEL	SHEET
COLUMBUS, OHIO 43218-3990		C	15

TEST WAVEFORMS

PARAMETER	٧x	OUTPUT WAVEFORM - MEASUREMENT LEVEL
t _{ER (-)}	1.5 V	V _{OH} 0.5 V V _X
tER(+)	2.6 V	V _{OL} V _X
^t EA (+)	1.5 V	V _X 0.5 V 1
t _{EA} (-)	V _{the}	V _X 0.5 V V _{OL}

INPUT PULSES

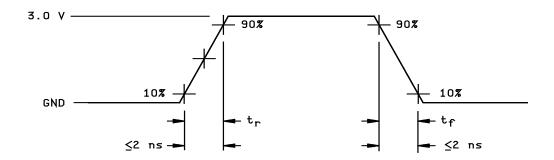
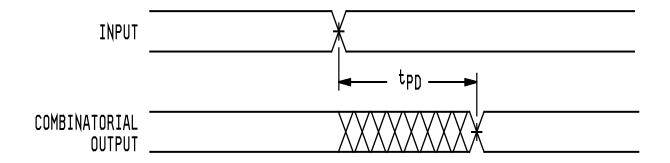


FIGURE 2. <u>Output load circuits and test conditions</u> - Continued.

STANDARD MICROCIRCUIT DRAWING	SIZE A		5962-99519
DLA LAND AND MARITIME		REVISION LEVEL	SHEET
COLUMBUS, OHIO 43218-3990		C	16

COMBINATORIAL OUTPUT



LATCHED OUTPUT

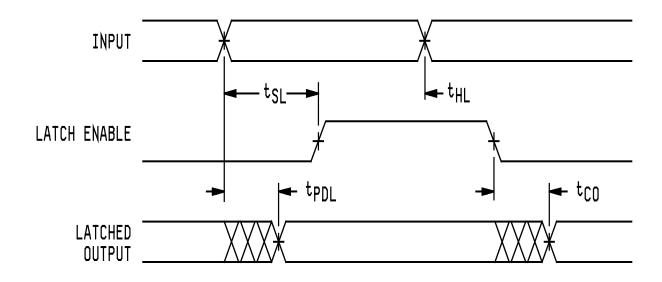


FIGURE 3. Switching waveforms.

STANDARD MICROCIRCUIT DRAWING	SIZE A		5962-99519
DLA LAND AND MARITIME COLUMBUS, OHIO 43218-3990		REVISION LEVEL C	SHEET 17

REGISTERED INPUT REGISTERED INPUT **-** tIΗ tis-INPUT REGISTER CLOCK tICO → COMBINATORIAL OUTPUT - tWH -CLOCK CLOCK TO CLOCK INPUT REGISTER CLOCK tics -- tscs -OUTPUT REGISTER CLOCK LATCHED INPUT LATCHED INPUT **←** tIH LATCH ENABLE · t_{PDL} ➡ tico COMBINATORIAL OUTPUT t_{WL} t⋈H LATCH ENABLE

FIGURE 3. <u>Switching waveforms</u> - Continued.

STANDARD MICROCIRCUIT DRAWING	SIZE A		5962-99519
DLA LAND AND MARITIME		REVISION LEVEL	SHEET
COLUMBUS, OHIO 43218-3990		C	18

LATCHED INPUT AND OUTPUT LATCHED OUTPUT INPUT LATCH ENABLE OUTPUT LATCH ENABLE LATCHED ENABLE LATCHED INPUT AND OUTPUT LATCHED INPUT AND OUTPUT LATCHED INPUT AND OUTPUT LATCHED INPUT AND OUTPUT LATCHED INPUT AND OUTPUT

ASYNCHRONOUS RESET

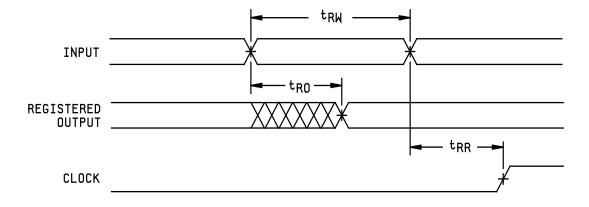
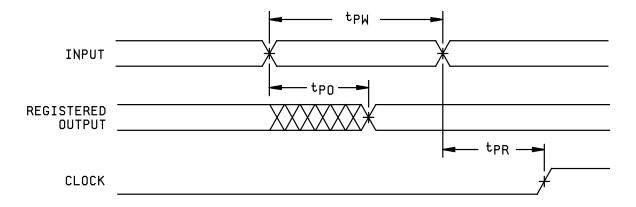


FIGURE 3. <u>Switching waveforms</u> - Continued.

STANDARD MICROCIRCUIT DRAWING	SIZE A		5962-99519
DLA LAND AND MARITIME		REVISION LEVEL	SHEET
COLUMBUS, OHIO 43218-3990		C	19

ASYNCHRONOUS PRESET



OUTPUT ENABLE/DISABLE

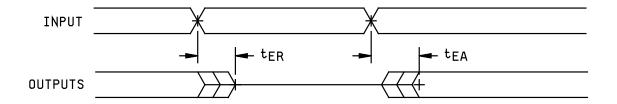
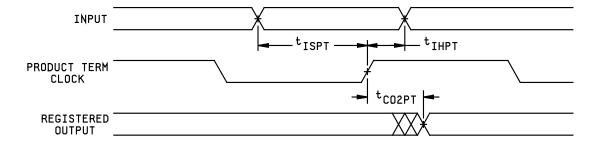


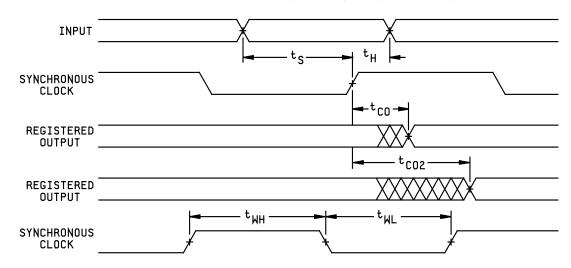
FIGURE 3. <u>Switching waveforms</u> - Continued.

STANDARD MICROCIRCUIT DRAWING	SIZE A		5962-99519
DLA LAND AND MARITIME COLUMBUS, OHIO 43218-3990		REVISION LEVEL C	SHEET 20

REGISTERED OUTPUT WITH PRODUCT TERM CLOCKING INPUT COMING FROM ADJACENT BURIED REGISTER



REGISTERED OUTPUT WITH SYNCHRONOUS CLOCKING



REGISTERED OUTPUT WITH PRODUCT TERM CLOCKING INPUT GOING THROUGH THE ARRAY

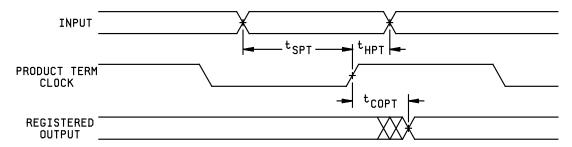
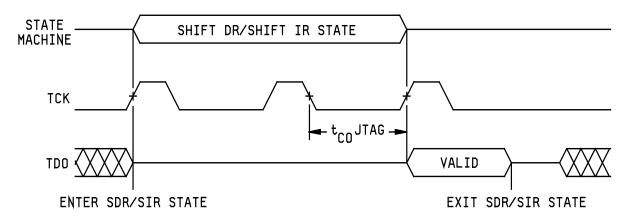


FIGURE 3. Switching waveforms - Continued.

STANDARD MICROCIRCUIT DRAWING	SIZE A		5962-99519
DLA LAND AND MARITIME COLUMBUS, OHIO 43218-3990		REVISION LEVEL C	SHEET 21

JTAG TDO VALID DELAY TIMING DIAGRAM



JTAG TMS/TDI SETUP AND HOLD DIAGRAMS

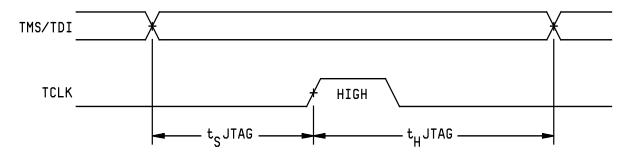


FIGURE 3. Switching waveforms - Continued.

STANDARD MICROCIRCUIT DRAWING	SIZE A		5962-99519
DLA LAND AND MARITIME COLUMBUS, OHIO 43218-3990		REVISION LEVEL C	SHEET 22

- 4.5 <u>Delta measurements for device class V.</u> Delta measurements, as specified in table IIA, shall be made and recorded before and after the required burn-in screens and steady-state life tests to determine delta compliance. The electrical parameters to be measured, with associated delta limits are listed in table IIB. The device manufacturer may, at his option, either perform delta measurements or within 24 hours after life test perform final electrical parameter tests, subgroups 1, 7, and 9.
- 4.6 <u>Erasure procedures</u>. Erasure procedures shall be as specified by the device manufacturer and shall be made available upon request.
- 4.7 <u>Programming procedures</u>. The programming procedures shall be as specified by the device manufacturer and shall be made available upon request.
 - 5. PACKAGING
- 5.1 <u>Packaging requirements</u>. The requirements for packaging shall be in accordance with MIL-PRF-38535 for device classes Q and V or MIL-PRF-38535, appendix A for device class M.
 - 6. NOTES
- 6.1 <u>Intended use</u>. Microcircuits conforming to this drawing are intended for use for Government microcircuit applications (original equipment), design applications, and logistics purposes.
- 6.1.1 <u>Replaceability</u>. Microcircuits covered by this drawing will replace the same generic device covered by a contractor prepared specification or drawing.
 - 6.1.2 Substitutability. Device class Q devices will replace device class M devices.
- 6.2 <u>Configuration control of SMD's</u>. All proposed changes to existing SMD's will be coordinated with the users of record for the individual documents. This coordination will be accomplished using DD Form 1692, Engineering Change Proposal.
- 6.3 <u>Record of users</u>. Military and industrial users should inform DLA Land and Maritime when a system application requires configuration control and which SMD's are applicable to that system. DLA Land and Maritime will maintain a record of users and this list will be used for coordination and distribution of changes to the drawings. Users of drawings covering microelectronic devices (FSC 5962) should contact DLA Land and Maritime-VA, telephone (614) 692-0544.
- 6.4 <u>Comments</u>. Comments on this drawing should be directed to DLA Land and Maritime-VA, Columbus, Ohio 43218-3990, or telephone (614) 692-0540.
- 6.5 <u>Abbreviations, symbols, and definitions</u>. The abbreviations, symbols, and definitions used herein are defined in MIL-PRF-38535 and MIL-HDBK-1331.
 - 6.6 Sources of supply.
- 6.6.1 <u>Sources of supply for device classes Q and V.</u> Sources of supply for device classes Q and V are listed in QML-38535. The vendors listed in QML-38535 have submitted a certificate of compliance (see 3.6 herein) to DLA Land and Maritime-VA and have agreed to this drawing.
- 6.6.2 <u>Approved sources of supply for device class M.</u> Approved sources of supply for class M are listed in MIL-HDBK-103. The vendors listed in MIL-HDBK-103 have agreed to this drawing and a certificate of compliance (see 3.6 herein) has been submitted to and accepted by DLA Land and Maritime-VA.

STANDARD MICROCIRCUIT DRAWING	SIZE A		5962-99519
DLA LAND AND MARITIME COLUMBUS, OHIO 43218-3990		REVISION LEVEL C	SHEET 23

STANDARD MICROCIRCUIT DRAWING BULLETIN

DATE: 11-11-02

Approved sources of supply for SMD 5962-99519 are listed below for immediate acquisition information only and shall be added to MIL-HDBK-103 and QML-38535 during the next revision. MIL-HDBK-103 and QML-38535 will be revised to include the addition or deletion of sources. The vendors listed below have agreed to this drawing and a certificate of compliance has been submitted to and accepted by DLA Land and Maritime -VA. This information bulletin is superseded by the next dated revision of MIL-HDBK-103 and QML-38535. DLA Land and Maritime maintains an online database of all current sources of supply at http://www.landandmaritime.dla.mil/Programs/Smcr/.

Standard microcircuit drawing PIN <u>1</u> /	Vendor CAGE number	Vendor similar PIN <u>2</u> /
5962-9951901QYA	<u>3</u> /	CY37064P44-125YMB
5962-9951902QYA	<u>3</u> /	CY37064P44-154YMB

- 1/ The lead finish shown for each PIN representing a hermetic package is the most readily available from the manufacturer listed for that part. If the desired lead finish is not listed, contact the vendor to determine its availability.
- <u>Caution</u>. Do not use this number for item acquisition. Items acquired to this number may not satisfy the performance requirements of this drawing.
- 3/ Not available from an approved source. The last known source is listed below.

 Vendor CAGE number
 Vendor name and address

 65786
 Cypress Semico

Cypress Semiconductor 3901 North First Street San Jose, CA 95134

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